

APT2012PD1C 2.0 x 1.25 mm Photodiode

DESCRIPTION

- Made with PIN silicon photodiode chips

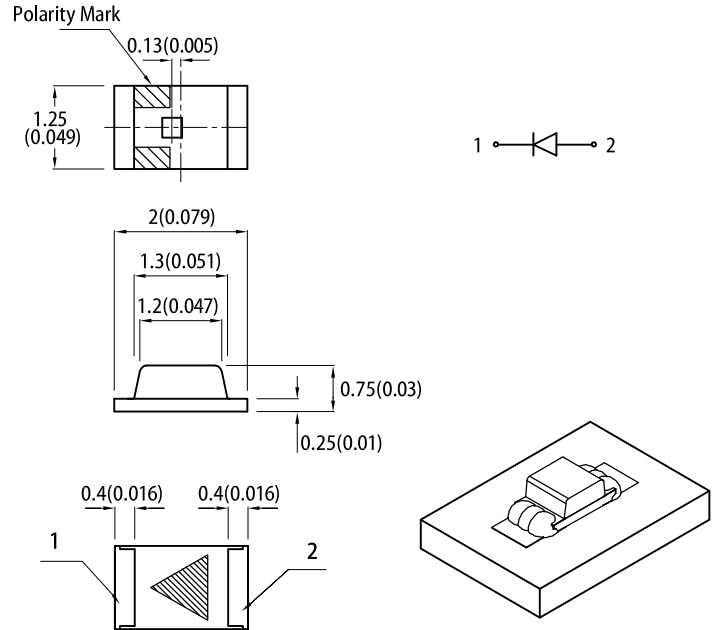
FEATURES

- 2.0 mm x 1.25 mm SMD LED, 0.75 mm thickness
- Mechanically and spectrally matched to infrared emitting LED lamp
- Package matched with IR emitter APT2012F3C
- Water Clear lens
- Package: 2000 pcs / reel
- Moisture sensitivity level: 3
- Halogen-free
- RoHS compliant

APPLICATIONS

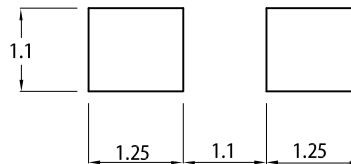
- Infrared applied systems
- Optoelectronic switches
- Photodetector control circuits
- Sensor technology

PACKAGE DIMENSIONS



RECOMMENDED SOLDERING PATTERN

(units : mm; tolerance : ± 0.1)



Notes:

- All dimensions are in millimeters (inches).
- Tolerance is ±0.1 (0.004") unless otherwise noted.
- The specifications, characteristics and technical data described in the datasheet are subject to change without prior notice.
- The device has a single mounting surface. The device must be mounted according to the specifications.

ABSOLUTE MAXIMUM RATINGS at T_A=25°C

Parameter	Maximum Ratings	Units
Power Dissipation	150	mW
Operating Temperature	-40 to +85	°C
Storage Temperature	-40 to +85	°C

Note:

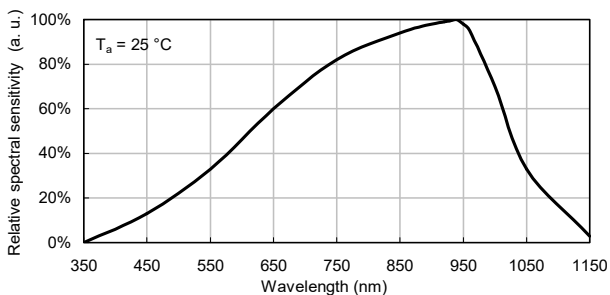
1. Relative humidity levels maintained between 40% and 60% in production area are recommended to avoid the build-up of static electricity – Ref JEDEC/JESD625-A and JEDEC/J-STD-033.

ELECTRICAL / OPTICAL CHARACTERISTICS at $T_A=25^\circ\text{C}$

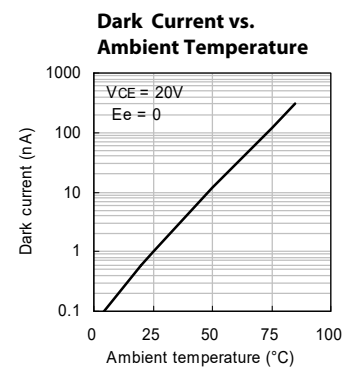
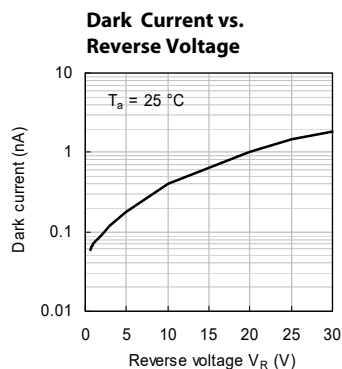
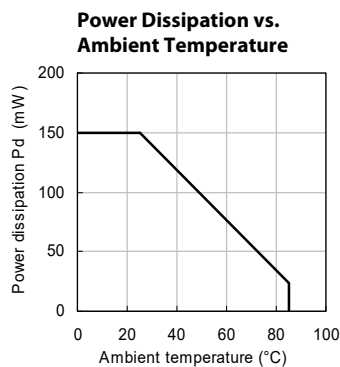
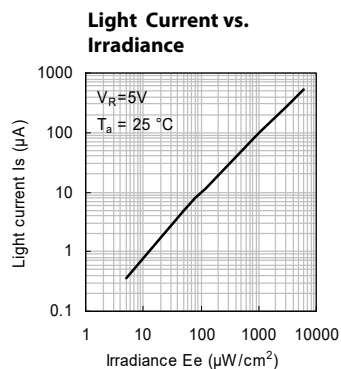
Parameter	Symbol	Min.	Typ.	Max.	Units	Test Conditions
Reverse Break Down Voltage	$V_{(BR)R}$	33	170	-	V	$I_R = 100\mu\text{A}$ $H = 0\text{mW}/\text{cm}^2$
Reverse Dark Current	$I_{D(R)}$	-	-	10	nA	$V_R = 10\text{V}$ $H = 0\text{mW}/\text{cm}^2$
Open Circuit Voltage	V_{OC}	-	390	-	mV	$\lambda = 940\text{nm}$ $H = 5\text{mW}/\text{cm}^2$
Rise Time	t_r	-	6	-	nS	$V_R = 10\text{V}$ $\lambda = 940\text{nm}$ $R_L = 1000\Omega$
Fall Time	t_f	-	6	-	nS	
Light Current	I_S	4	8	-	μA	$V_R = 5\text{V}$ $E_e = 0.08\text{mW}/\text{cm}^2$ $\lambda = 940\text{nm}$
Total Capacitance	C_T	-	5	-	pF	$V_R = 10\text{V}$ $F = 1\text{MHz}$ $H = 0\text{mW}/\text{cm}^2$
Range of Spectral Bandwidth	$\lambda_{0.1}$	420	-	1120	nm	-
Wavelength of Peak Sensitivity	λ_p	-	940	-	nm	-

TECHNICAL DATA

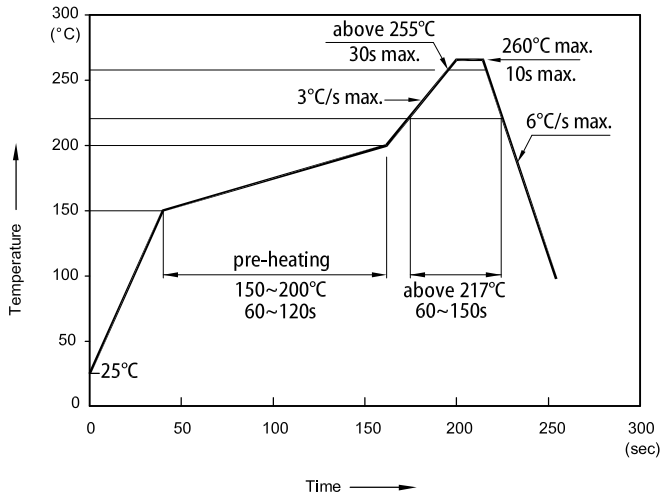
RELATIVE SPECTRAL SENSITIVITY vs. WAVELENGTH



PHOTODIODE

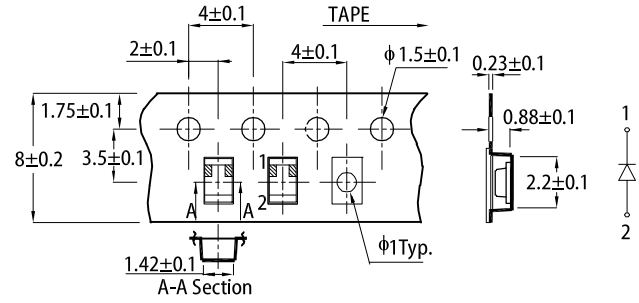


REFLOW SOLDERING PROFILE for LEAD-FREE SMD PROCESS

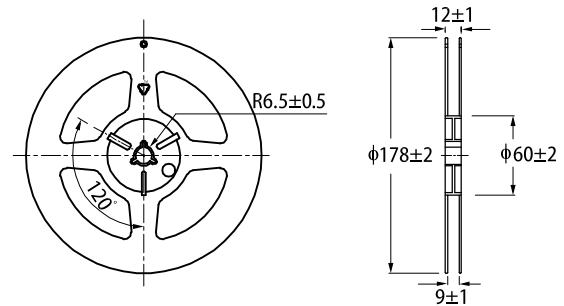


- Notes:
1. Don't cause stress to the LEDs while it is exposed to high temperature.
 2. The maximum number of reflow soldering passes is 2 times.
 3. Reflow soldering is recommended. Other soldering methods are not recommended as they might cause damage to the product.

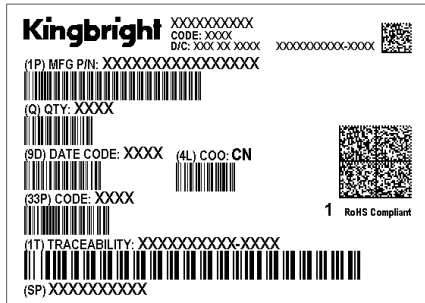
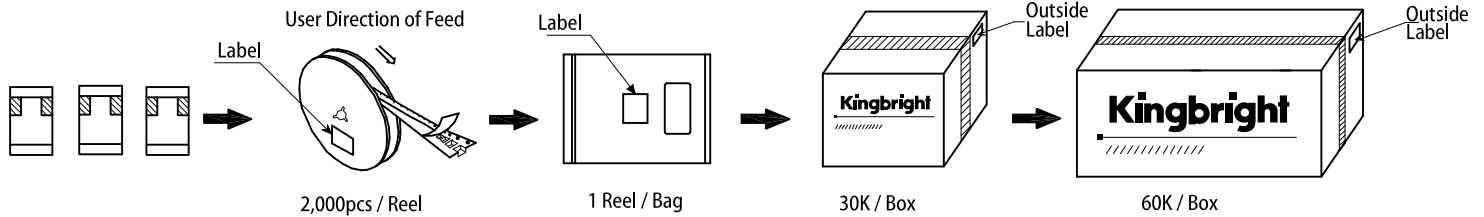
TAPE SPECIFICATIONS (units : mm)



REEL DIMENSION (units : mm)



PACKING & LABEL SPECIFICATIONS



PRECAUTIONARY NOTES

1. The information included in this document reflects representative usage scenarios and is intended for technical reference only.
2. The part number, type, and specifications mentioned in this document are subject to future change and improvement without notice. Before production usage customer should refer to the latest datasheet for the updated specifications.
3. When using the products referenced in this document, please make sure the product is being operated within the environmental and electrical limits specified in the datasheet. If customer usage exceeds the specified limits, Kingbright will not be responsible for any subsequent issues.
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